

DATA SHEET



BAS40L Schottky barrier diode

Product specification

2003 May 20

Schottky barrier diode

BAS40L

FEATURES

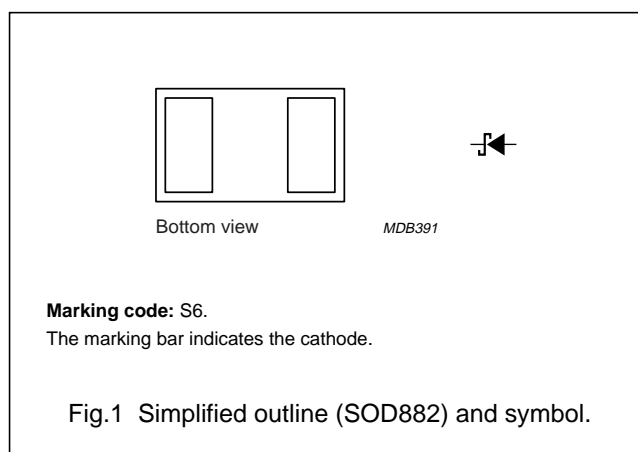
- Low diode capacitance
- Low forward voltage
- Guard ring protected
- High breakdown voltage
- Leadless ultra small plastic package (1 mm × 0.6 mm × 0.5 mm)
- Boardspace 1.17 mm² (approx. 10% of SOT23)
- Power dissipation comparable to SOT23.

APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Mobile communication, digital (still) cameras, PDAs and PCMCIA cards.

DESCRIPTION

Planar Schottky barrier diode with an integrated guard ring for stress protection. Encapsulated in a SOD882 leadless ultra small plastic package.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V_R	continuous reverse voltage		–	40	V
I_F	continuous forward current		–	120	mA
I_{FRM}	repetitive peak forward current	$t_p \leq 1\text{ s}; \delta \leq 0.5$	–	120	mA
I_{FSM}	non-repetitive peak forward current	$t_p < 10\text{ ms}$	–	200	mA
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C

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ELECTRICAL CHARACTERISTICS

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V_F	continuous forward voltage	see Fig.2		
		$I_F = 1\text{ mA}$	380	mV
		$I_F = 10\text{ mA}$	500	mV
		$I_F = 40\text{ mA}$	1	V
I_R	continuous reverse current	$V_R = 30\text{ V}$; see Fig.3; note 1	1	μA
		$V_R = 40\text{ V}$; see Fig.3; note 1	10	μA
C_d	diode capacitance	$V_R = 0\text{ V}$; $f = 1\text{ MHz}$; see Fig.5	5	pF

Note

1. Pulse test: $t_p = 300\text{ }\mu\text{s}$; $\delta = 0.02$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Refer to SOD882 standard mounting conditions (footprint), FR4 with 60 μm copper strip line.

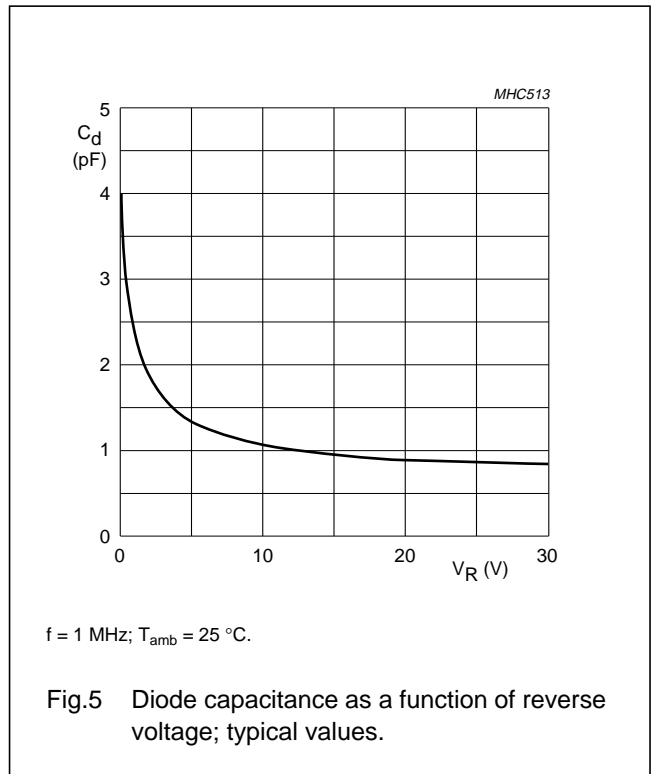
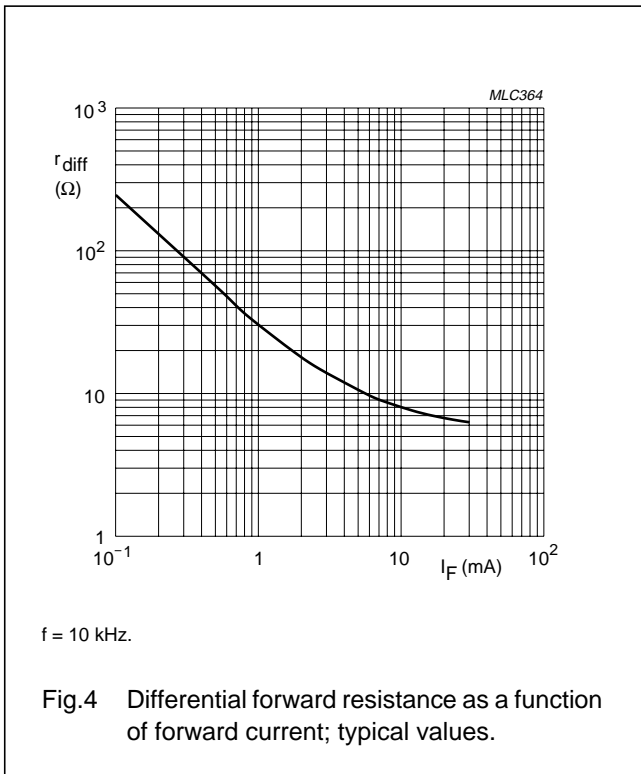
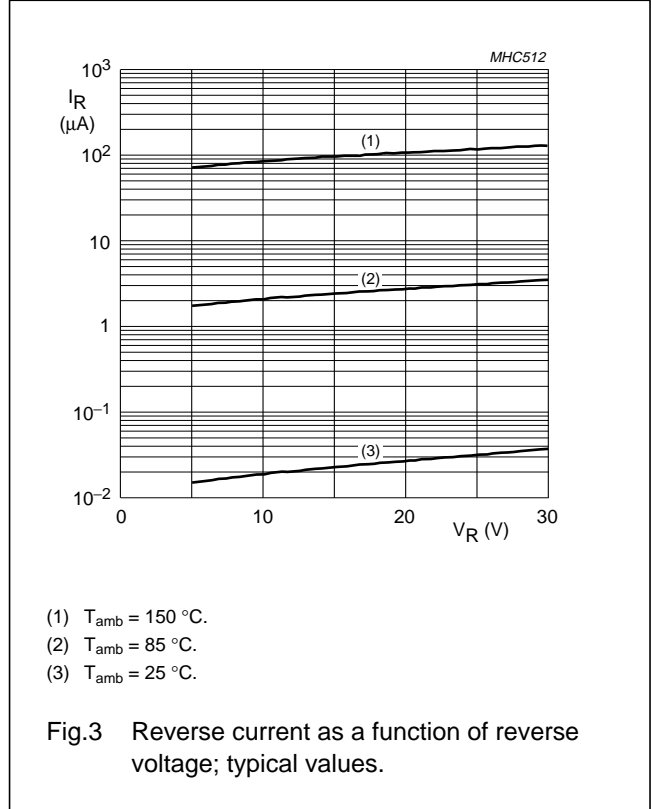
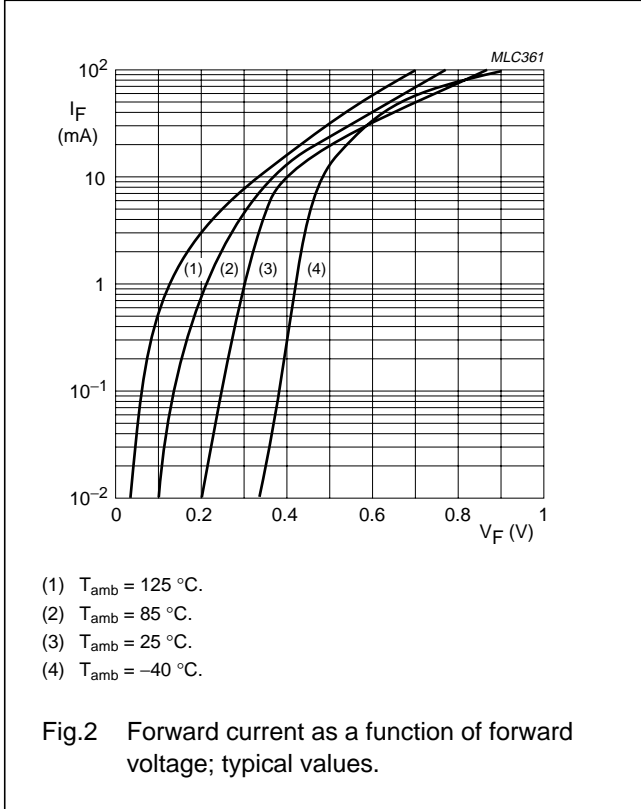
Soldering

Reflow soldering is the only recommended soldering method.

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GRAPHICAL DATA



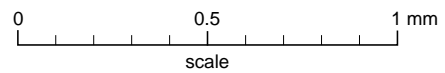
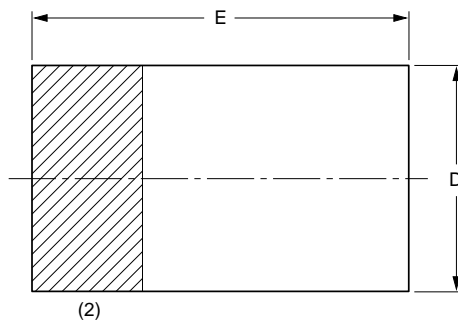
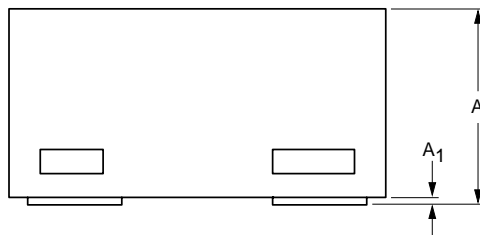
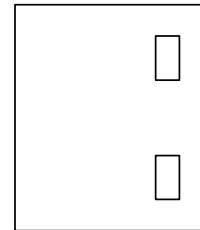
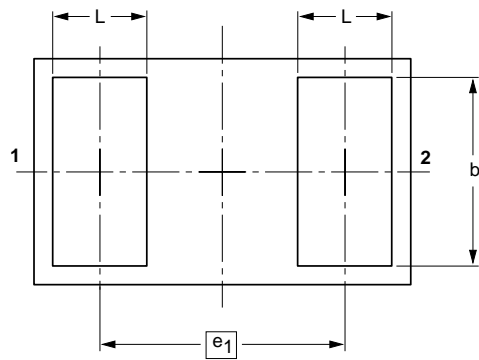
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PACKAGE OUTLINE

Leadless ultra small plastic package; 2 terminals; body 1.0 x 0.6 x 0.5 mm

SOD882



DIMENSIONS (mm are the original dimensions)

UNIT	A ⁽¹⁾	A ₁ max.	b	D	E	e ₁	L
mm	0.50 0.46	0.03	0.55 0.47	0.62 0.55	1.02 0.95	0.65	0.30 0.22

Notes

1. Including plating thickness
2. The marking bar indicates the cathode

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOD882						03-04-16 03-04-17

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Contact information

For additional information please visit <http://www.semiconductors.philips.com>. Fax: +31 40 27 24825

For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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